OPTICAL, STRUCTURAL AND ELECTRICAL PROPERTIES OF Zr DOPED CoSe FOR PHOTOVOLTAIC APPLICATION

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INTRODUCTION

Due to the wide range of applications of the nanocrystalline chalcogenide thin films, It has gained attention among researchers.

For the present work, ZrCoSe thin films has been synthesized by spray pyrolyysis techniques for PV application.

OBJECTIVES

To synthesize zirconium dope cobalt selenide (Zn/CoSe) using

spray pyrolysis techniques.

To characterisce Zn/CoSe thin films to determine thre structur-

al, optical, elemental and electrical properties of the films.

RESULTS AND DISCUSSION







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Fig.1. XRD pattern of CoSe and Zr/CoSe materials

Figs 2. A, B and C are micrographs of CoSe control, CoSe/Zr 0.01 mol% and CoSe/Zr 0.04 mol% respectively.



CONCLUSION

Spray pyrolysis technique was successfully used for the deposition of CoSe/Zr thin films. Doping CoSe with Zirconium made the absorbance more prominent at the UV region. As the dopant percentage concentration increased the absorbance improved significantly. Temperature increase significantly enhanced better performance of Zr/CoSe material.

